NSN 5962-01-365-1425

Memory Microcircuit - Page 1 of 1

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Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Scadc e/i fscm k0656
Features Provided:
Programmed
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
20 input
Terminal Surface Treatment:
Solder
Product Name:
Programmed device (pal)
Voltage Rating And Type Per Characteristic:
-1.0 volts absolute input and 22.0 volts absolute input
Memory Device Type:
Pal
Hybrid Technology Type:
Monolithic
Test Data Document:
K0656-9986-ccrm drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,
etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
24 printed circuit
Specification Data:
96906-mil-std-883 government standard
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig: